

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Continuation Application of )  
Hisashi OHTANI et al. )  
Based On Serial No. 08/479,211 ) Art Unit: 1104  
Which Was Filed: June 7, 1995 ) Examiner: L. Radomsky  
For: METHOD FOR )  
MANUFACTURING )  
SEMICONDUCTOR DEVICE ) Date: February 27, 1997

PRELIMINARY AMENDMENT

Honorable Assistant Commissioner for Patents  
Washington, D.C. 20231

Sir:

Please preliminarily amend the subject application as follows:

IN THE CLAIMS:

Please cancel claims 1-18 without prejudice.

Please add new claims 19-33 as follows:

--19. A method of manufacturing a semiconductor device comprising

D. S. M. 5/23/97